

BT136

主要参数 MAIN CHARACTERISTICS

$I_{T(RMS)}$	4A
V_{DRM}	600V or 800V
I_{GT}	10mA

用途

- 交流开关
- 相位控制

APPLICATIONS

- AC switching
- Phase control

产品特性

- 平面钝化芯片，高可靠性和一致性
- 低通态电流和高浪涌电流能力
- 环保 RoHS 产品
- 通过 UL 认证：E258645

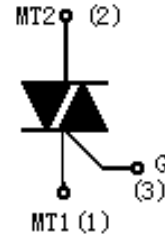
FEATURES

- Planar chip for reliability and uniform
- Low on-state voltage and High I_{TSM}
- RoHS products
- UL: E258645

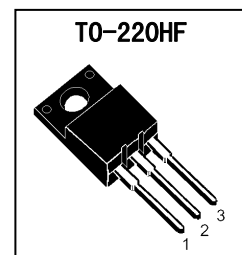
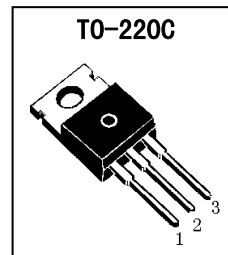
订货信息 ORDER MESSAGES

订货型号 Order code	印记 Marking	封装 Package	包装 Packaging
BT136-O-C-N-B	BT136	TO-220C	条管 Tube
BT136-O-HF-N-B	BT136	TO-220HF	条管 Tube

封装 Package



序号 Pin	引线名称 Description
1	主电极 1 MT1
2	主电极 2 MT2
3	门极 G



绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^\circ\text{C}$)

项 目 Parameter	符 号 Symbol	试 验 条 件 Condition	数 值 Value	单 位 Unit
重复峰值断态电压 Repetitive peak off-state voltage	V_{DRM}		± 600 ± 800	V
通态方均根电流 On-state RMS current	$I_{\text{T(RMS)}}$	full sine wave	4	A
非重复浪涌峰值通态电流 Non-repetitive surge peak on-state current	I_{TSM}	full sine wave ,t=20ms	25	A
		full sine wave ,t=16.7ms	27	A
		I^2t	t=10ms	3.1
通态电流临界上升率 Repetitive rate of rise of on-state current after triggering	di/dt	$I_{\text{TM}}=6\text{A}$, $I_{\text{G}}=0.2\text{A}$, $di_{\text{G}}/dt=0.2\text{A}/\mu\text{s}$	50	$\text{A}/\mu\text{s}$
峰值门极电流 Peak gate current	I_{GM}		2	A
峰值门极电压 Peak gate voltage	V_{GM}		5	V
峰值门极功率 Peak gate power	P_{GM}		5	W
平均门极功率 Average gate power	$P_{\text{G(AV)}}$	over any 20ms period	0.5	W
存储温度 Storage temperature	T_{stg}		-40~150	$^\circ\text{C}$
操作结温 Operation junction temperature	T_{VJ}		125	$^\circ\text{C}$



电特性 ELECTRICAL CHARACTERISTIC ($T_c=25^\circ\text{C}$)

项 目 Parameter	符 号 Symbol	测 试 条 件 Condition		最小 Min	典型 Typ	最大 Max	单位 Unit
峰值重复断态电流 Peak Repetitive Blocking Current	I_{DRM}	$V_{\text{DM}}=V_{\text{DRM}}$, $T_j=125^\circ\text{C}$, gate open		-	-	0.5	mA
峰值通态电压 Peak on-state voltage	V_{TM}	$I_{\text{TM}}=5\text{A}$		-	1.4	1.7	V
门极触发电流 Gate trigger current	I_{GT}	$V_{\text{DM}}=12\text{V}$, $R_L=100\ \Omega$	MT1(-),MT2(+),G(+)	-	2.5	10	mA
			MT1(-),MT2(+),G(-)	-	4.0	10	mA
			MT1(+),MT2(-),G(-)	-	5.0	10	mA
			MT1(+),MT2(-),G(+)	-	11	25	mA
门极触发电压 Gate trigger voltage	V_{GT}	$V_{\text{DM}}=12\text{V}$, $R_L=100\ \Omega$	MT1(-),MT2(+),G(+)	-	-	1.5	V
			MT1(-),MT2(+),G(-)	-	-	1.5	V
			MT1(+),MT2(-),G(-)	-	-	1.5	V
维持电流 Holding current	I_{H}	$V_{\text{DM}}=12\text{V}$, $I_{\text{GT}}=0.1\text{A}$		-	-	20	mA
擎住电流 Latching current	I_{L}	$V_{\text{DM}}=12\text{V}$, $I_{\text{GT}}=0.1\text{A}$	MT1(-),MT2(+),G(+)	-	3.0	15	mA
			MT1(-),MT2(+),G(-)	-	10	20	mA
			MT1(+),MT2(-),G(-)	-	2.5	15	mA
断态临界电压上升率 Rise of off- state voltage	dV/dt	$V_{\text{DM}}=67\% V_{\text{DRM(MAX)}}$, $T_j=125^\circ\text{C}$, gate open		-	50	-	V/ μs
门极开通时间 Gate controlled turn-on time	tgt	$I_{\text{TM}}=6\text{A}$, $V_{\text{DM}}=V_{\text{DRM(MAX)}}$, $I_{\text{G}}=0.1\text{A}$, $dI_{\text{G}}/dt=5\text{A}/\mu\text{S}$		-	2	-	μs

热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	条 件 Condition	最小 Min	典型 Typ	最大 Max	单位 Unit
结到管壳的热阻 Thermal resistance junction to case	$R_{\text{th(j-c)}}$	full cycle(TO-220C)			3.0	$^\circ\text{C}/\text{W}$
		full cycle(TO-220HF)			4.5	$^\circ\text{C}/\text{W}$

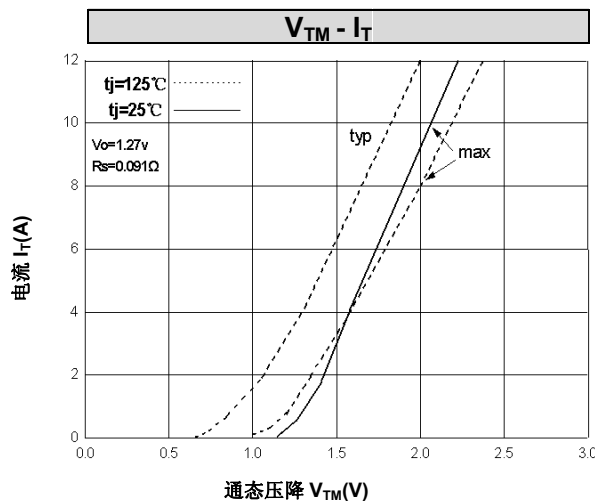
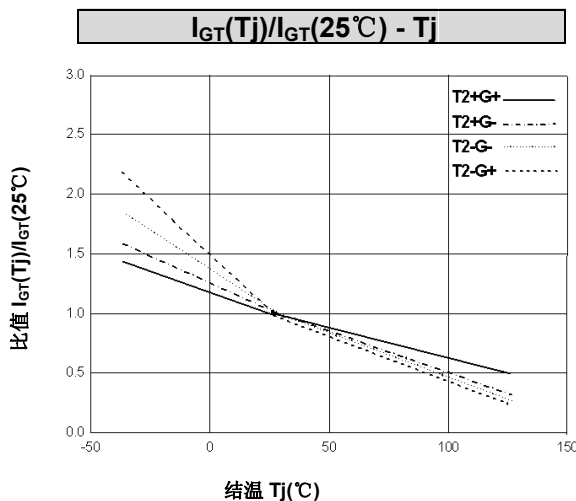
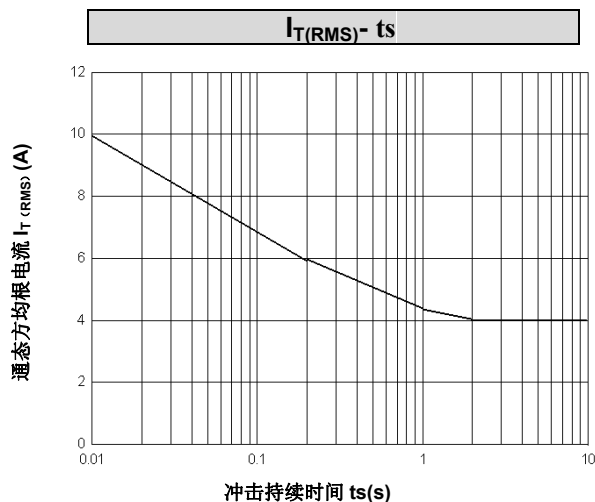
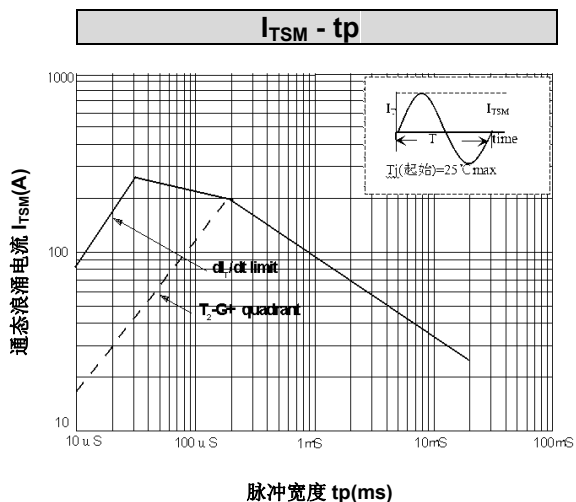
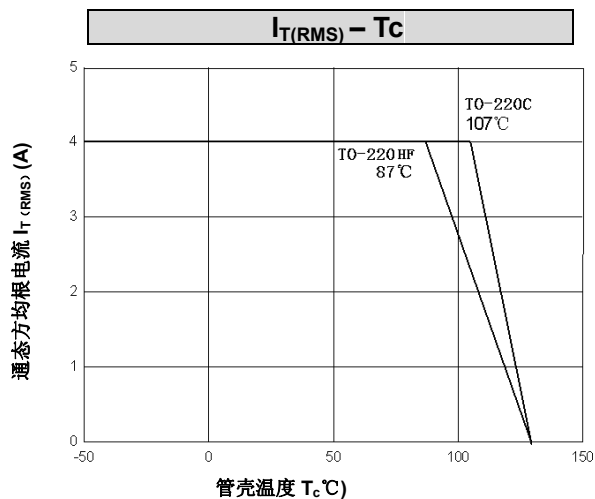
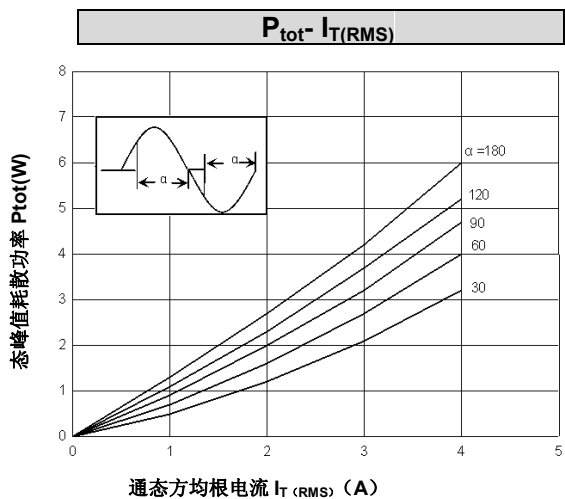
电绝缘特性 ELECTRICAL ISOLATION

项 目 Parameter	符 号 Symbol	条 件 Condition	数 值 Value	单位 Unit
绝缘电压 Isolation voltage	V_{ISOL}	1 minute, leads to mounting tab TO-220HF	2000	V





特征曲线 ELECTRICAL CHARACTERISTICS (curves)

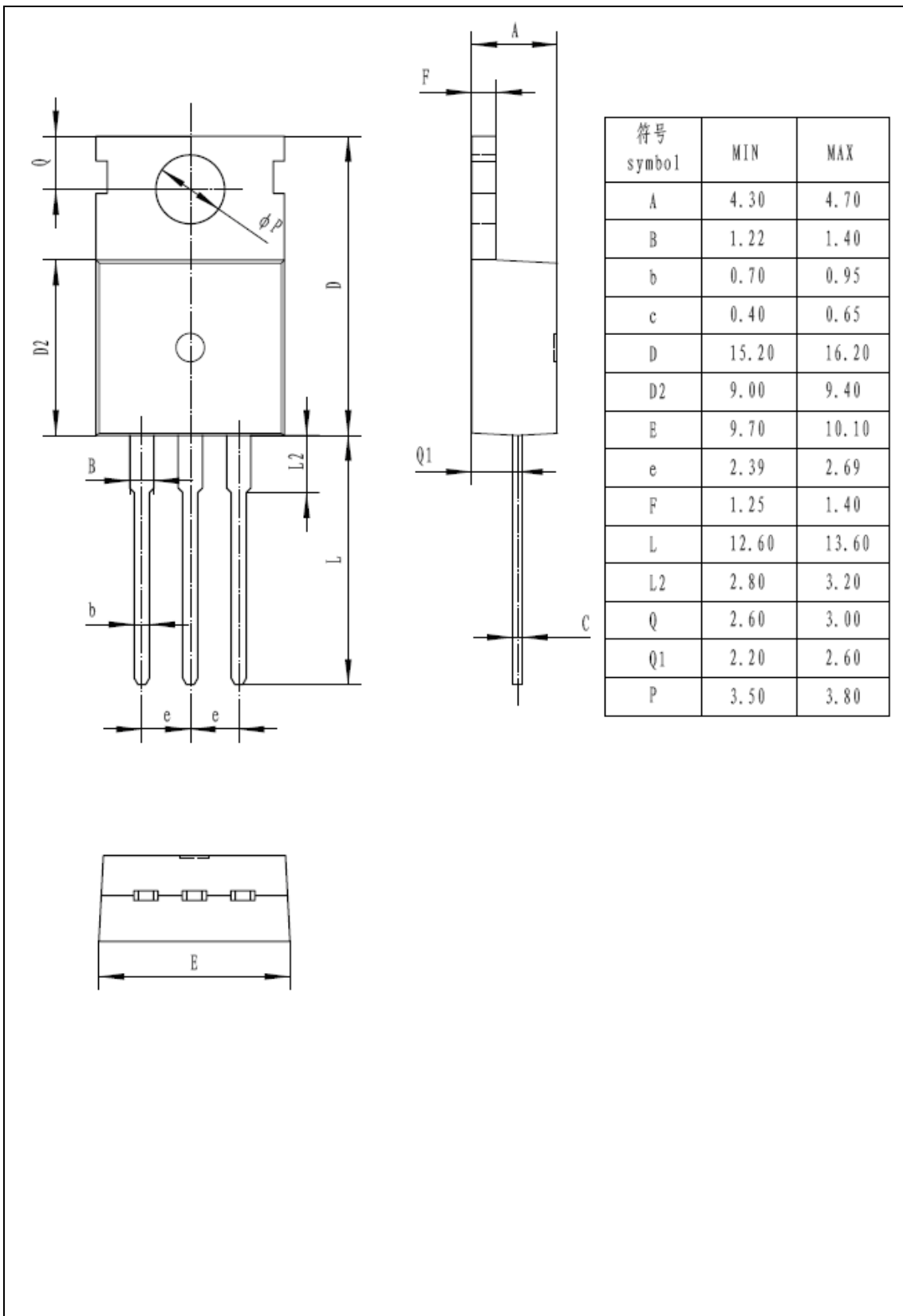




外形尺寸 PACKAGE MECHANICAL DATA

TO-220C

单位 Unit : mm

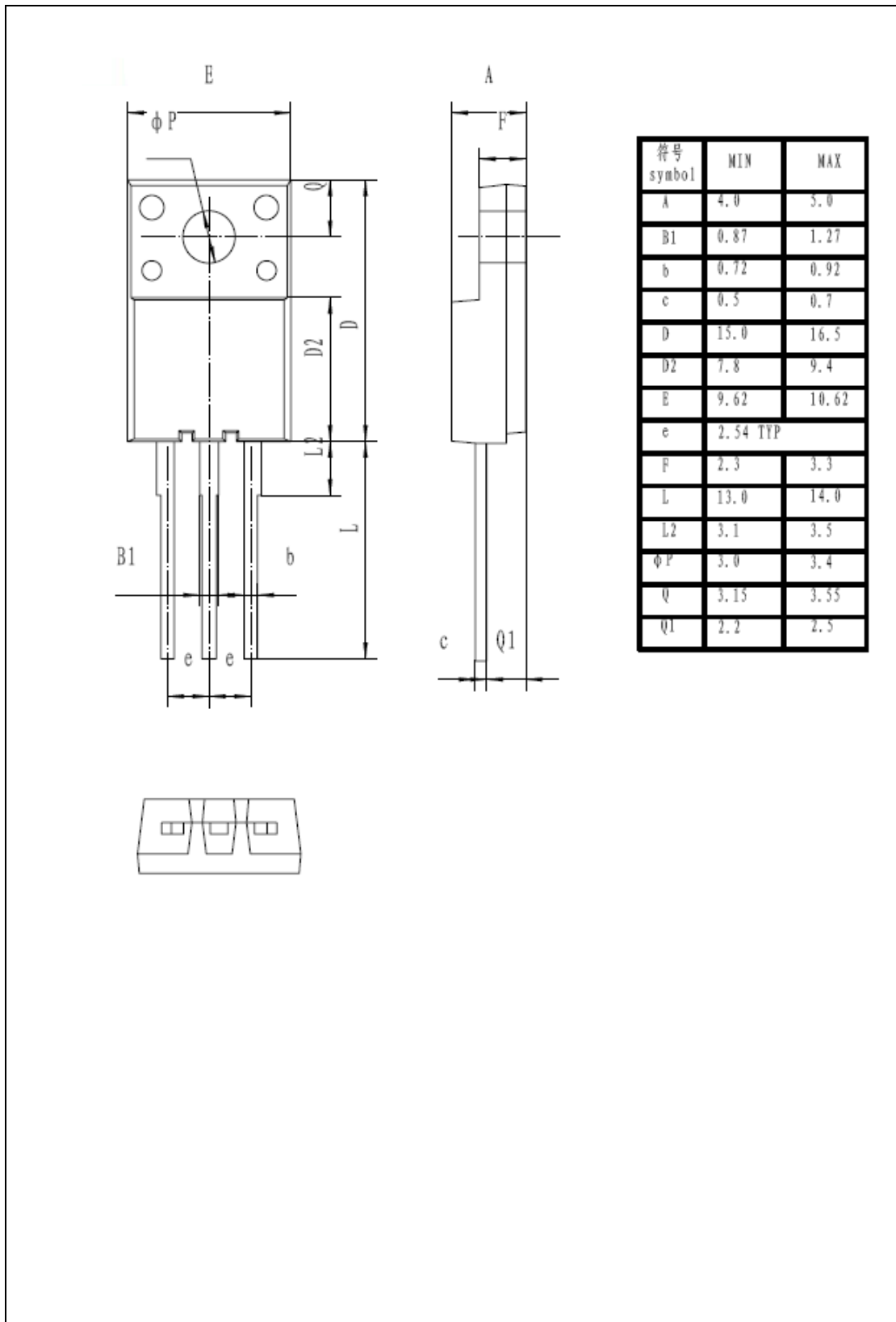




外形尺寸 PACKAGE MECHANICAL DATA

TO-220HF

单位 Unit : mm



**注意事项**

1. 吉林华微电子股份有限公司的产品销售分为直销和销售代理，无论哪种方式，订货时请与公司核实。
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3. 在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
4. 本说明书如有版本变更不另外告知

NOTE

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2. We strongly recommend customers check carefully on the trademark when buying our product, if there is any question, please don't be hesitate to contact us.
3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
4. Jilin Sino-microelectronics co., Ltd reserves the right to make changes in this specification sheet and is subject to change without prior notice.

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附录 (Appendix)：修订记录 (Revision History)

日期 Date	旧版本 Last Rev.	新版本 New Rev.	修订内容 Description of Changes
2009-5-15	200901E	200905F	中英文格式改版
2009-11-3	200905F	200911G	修改电话号码
2010-9-6	200911G	201009H	修改 TO-220C 外形
2015-10-22	201009H	201510I	修改热阻参数

